
**STRUCTURE, MAGNETIC AND OPTICAL
PROPERTIES OF MATERIALS**

Luminescent Mn²⁺-Doped MgO–Al₂O₃–ZrO₂–SiO₂ Sol–Gel Materials

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Abstract—Mn²⁺-doped MgO–Al₂O₃–ZrO₂–SiO₂ materials have been synthesized by the sol–gel method, and their structure, morphology, chemical composition, and luminescent properties have been studied using X-ray diffraction, scanning electron microscopy, EDX analysis, and luminescence spectroscopy. The sol–gel method has been shown to ensure high homogeneity of the chemical composition over the volume of the synthesized materials. The introduction of Mn into the composition of sol–gel materials significantly accelerates crystallization processes in them during heat treatment. The luminescence spectra of the materials display several groups of emission bands in the blue and yellow-red parts of the visible spectral range. The resulting materials are promising for use as phosphors in the lighting for plant production.

Keywords: defects, manganese, aluminum–magnesium spinel

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Various luminescent Mn²⁺-doped oxide materials have wide practical applications [1–12]. Mn²⁺ ions can occupy different structural positions in these materials ([MnO₄] or [MnO₆]), and the spectral and luminescent properties of these ions are very sensitive to the structure of their nearest environment [8–16]. This determines the efficiency of using Mn²⁺ ions as a component of various luminescent materials.

The splitting of the electronic levels of Mn²⁺ under the influence of the crystal field of the nearest environment determines the features of the spectral and luminescent properties of these ions in solid matrices. The Tanabe–Sugano diagram [17] is often used to describe this phenomenon in various matrices [4, 12, 15–19].

Figure 1 shows an illustrative Tanabe–Sugano diagram, constructed on the basis of data from [18, 20] and demonstrating the influence of the crystal field strength (CFS) on the splitting of energy levels of Mn²⁺ ions. According to the Tanabe–Sugano diagram, the spectral position of the emission band of the Mn²⁺ ion depends on the strength of the crystal field of its surroundings. The CFS of Mn²⁺ ions in a tetra-

hedral environment is noticeably weaker than that in an octahedral environment [12, 20].

Figure 1 shows that the luminescence bands of Mn²⁺ ions in both structural positions are associated with the electronic transition ⁴T₁(G) → ⁶A₁(S), but these bands are in different ranges of the visible spectrum. The Mn²⁺ ions in a tetrahedral coordination (Mn²⁺(IV)) exhibit green emission [15, 16, 20–22], while ions in an octahedral coordination ((Mn²⁺(VI)) luminesce in the yellow-red range of the spectrum [18, 20, 23, 24]. The authors of [25] also observed luminescence under the influence of UV radiation (λ_{ex} = 356 nm) in CaYAl₃O₇:Mn²⁺ crystals in the near-UV and blue ranges of the spectrum (bands with λ_{max} = 389 and 412 nm) and attributed it to the emission of Mn²⁺ ions.

At the same time, the introduction of Mn²⁺ ions into the crystal lattice of oxide materials leads to its distortion [26, 27] and the formation of structural defects, which affects the luminescent properties of materials [24, 27, 28]. In this case, luminescent centers in Mn²⁺-doped materials can be both intrinsic

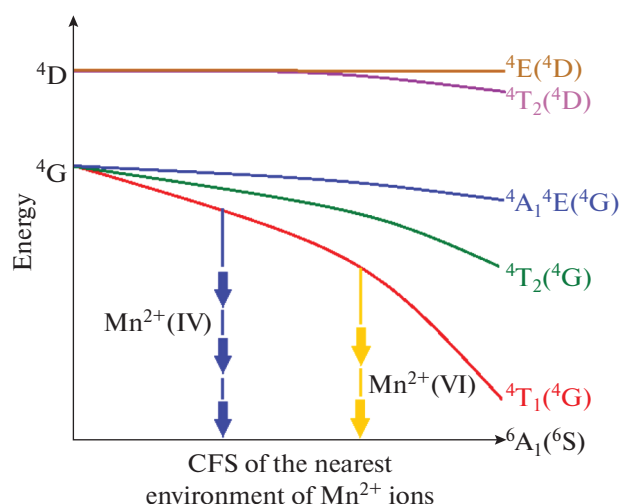


Fig. 1. Illustrative Tanabe–Sugano diagram constructed on the basis of data from [18, 20] and demonstrating the influence of the strength of the crystal field of the nearest environment on the splitting of energy levels of Mn^{2+} ions.

structural defects of the oxide matrices [22, 24, 27] and manganese ions [28, 29].

Various silicate glass-ceramics containing additives of manganese compounds have been synthesized and studied [1–3, 10, 11, 13, 20, 30]. It has been shown that these materials are promising for use as luminescent radiation converters in white LEDs [30]. It is known that many glass-ceramic materials contain several types of crystals [12, 31, 32], and structural design opens new opportunities for fabricating materials with luminescence bands in different spectral ranges [10].

In addition, Mn^{2+} ions found in some matrices, for example, in MgAl_2O_4 , can be oxidized to give Mn^{4+} ions, which replace Al^{3+} ions and have luminescence bands in the red range of the spectrum [15, 33, 34].

This approach is relevant for the development of luminescent materials that are promising for special lighting systems used in crop production. It is known that to accelerate plant growth, lamps have been developed and used that emit in two spectral ranges: in the blue and red range of the spectrum [35–37]. Considering the above-described features of the luminescent properties of Mn^{2+} ions, glass-ceramic materials in which these ions are embedded in various crystals and are in them in both tetrahedral and octahedral coordination can be promising for plant growing lighting technology.

The efficiency of using phosphors of the $\text{Ba}_{1.3}\text{Sr}_{1.7}\text{MgSi}_2\text{O}_8$ system containing two activator ions (Eu^{2+} and Mn^{2+}) as a component of glass-ceramic composites for agricultural lighting systems was experimentally demonstrated in [37]. The use of lamps based on these phosphors has been shown to increase the yield of the vegetable crop Romaine lettuce

by more than 50% compared to commercial greenhouse lamps. It should be noted, however, that the content of the rare earth component (Eu) in the phosphors developed in [37] is 6%, and this determines their rather high cost and the relevance of developing materials for technological lighting systems in greenhouses that do not contain expensive components.

Crystallization of glasses in the $\text{MgO–Al}_2\text{O}_3\text{–SiO}_2$ system leads to the formation of glass-ceramic materials containing various crystals [31, 32, 38]. These materials can be considered a glass-ceramic matrix for introducing Mn^{2+} ions into it [3], have high thermal stability and mechanical strength, and are used in various optical applications [31, 32, 38, 39]. By introducing cobalt compounds into the composition of these materials, heat-resistant light filters and passive Q switches were obtained [39].

The ionic radii of Mg^{2+} and Mn^{2+} are close (0.72 and 0.83 Å, respectively [40]), and Mn^{2+} can replace Mg^{2+} in the structure of many crystals [15, 41, 42]. It has been shown [3] that the introduction of MnO into the composition of glass-ceramic materials of the $\text{MgO–Al}_2\text{O}_3\text{–SiO}_2$ system additionally increases their high mechanical strength. In this work, it has been established that the introduction of manganese oxide somewhat changes the crystal structure of glass ceramics.

The crystalline phases formed upon the crystallization of glasses of the $\text{MgO–Al}_2\text{O}_3\text{–SiO}_2$ system (aluminum magnesium spinel; quartz-like solid solutions) can contain intrinsic structural defects that determine the luminescence of materials in the near-UV and blue parts of the spectrum. In particular, aluminum magnesium spinel under short-wave UV light shows intense luminescence bands with maxima at 316, 380, 400, and 460 nm [43]. In this spectral range, luminescence of structural defects characteristic of silica obtained by the sol–gel route, described in detail in [44], can also be observed. In addition, studying the luminescent properties of aluminosilicate glasses presented in [29] indicates a high efficiency (>85%) of excitation energy transfer from structural defects [SiO_{4-x}] to Mn^{2+} ions. Based on the literature data, we can conclude that the study of Mn^{2+} -doped $\text{MgO–Al}_2\text{O}_3\text{–SiO}_2$ materials is relevant.

The present work focuses on the synthesis and study of Mn^{2+} -doped $\text{MgO–Al}_2\text{O}_3\text{–ZrO}_2\text{–SiO}_2$ materials, which do not contain expensive rare-earth components. The traditional method of glass melting for this system and subsequent production of glass-ceramic materials requires the use of high synthesis temperatures, so that it is difficult to obtain homogeneous samples using this method. Therefore, in this work, a low-temperature sol–gel method was used to obtain Mn^{2+} -doped $\text{MgO–Al}_2\text{O}_3\text{–ZrO}_2\text{–SiO}_2$ materials.

EXPERIMENTAL

The materials were synthesized by the sol–gel method using soluble metal salts and tetraethoxysilane (TEOS). Aqueous solutions of Mg(NO₃)₂, Al(NO₃)₃, ZrOCl₂, and MnSO₄ in a given ratio were mixed at room temperature with TEOS, dimethylformamide, and 2-propanol.

After gelation, the material samples were dried at 70°C in an oven and subjected to heat treatment in an electric muffle furnace for 2 h at temperatures of 600, 900, or 1150°C. The chemical composition of the materials is presented in Table 1. Gel **1** was synthesized without the addition of manganese, and gel **2** contained manganese.

The crystal structure of the resulting powders was studied by powder X-ray diffraction analysis on a Rigaku Ultima IV X-ray diffractometer. The morphology of powder grains was studied using a Vega3 Tescan scanning electron microscope equipped with an Oxford Instruments Advanced Aztec Energy unit for energy-dispersive X-ray analysis. Luminescence and luminescence excitation spectra were measured on a Perkin Elmer LS 50B spectrofluorimeter.

RESULTS AND DISCUSSION

Figure 2 shows X-ray diffraction patterns of samples heat-treated at various temperatures. It is seen that the initial gels and powders calcined at 600°C are amorphous. Heat treatment at 1150°C leads to the formation of various crystalline phases: cordierite, enstatite, ZrO₂, and β-quartz solid solutions. It is known that these crystals often form during the crystallization of glasses of the MgO–Al₂O₃–ZrO₂–SiO₂ system and the formation of glass-ceramics [3, 32]. Note that the

Table 1. Chemical composition of the synthesized oxide composites (mol %)

Sample	MgO	Al ₂ O ₃	SiO ₂	MnO
1	11.2	16.5	72.3	–
2	9.9	16.9	68.8	4.4

The nominal chemical composition of the composites, expressed in elemental oxides and calculated from the chemical composition of the sols, is given.

nature of the thermal evolution of the crystal structure of materials synthesized by the sol–gel method is similar to the changes observed during the crystallization of MgO–Al₂O₃–ZrO₂–SiO₂ glasses described in [32].

Comparison of Figs. 2a and 2b shows that the introduction of manganese into the composition of materials leads to a considerable acceleration of crystallization processes in them. The significant influence of manganese additives on the crystallization processes of silicate materials has been reported earlier [3, 41].

Figures 3 and 4 show SEM images of initial gels **1** and **2** (Figs. 3a, 4) and gels heat-treated at 600°C (Fig. 4b), 900°C (Fig. 4c), and 1150°C (Figs. 3b, 4d). The initial gels contain large, irregularly shaped aggregates consisting of submicron particles 100–200 nm in size. The particle size in powders changes noticeably with increasing heat treatment temperature, and the structure of heat-treated gels consists of submicron particles.

Figure 5 shows the photoluminescence and luminescence excitation spectra of glass-crystalline material **2** obtained after heat treatment at (a) 900 and (b) 1150°C. The luminescence spectrum shows emission bands in the blue ($\lambda_{\max} \sim 410$ nm) and yellow-red ($\lambda_{\max} = 560$ –640 nm) spectral ranges. The observed

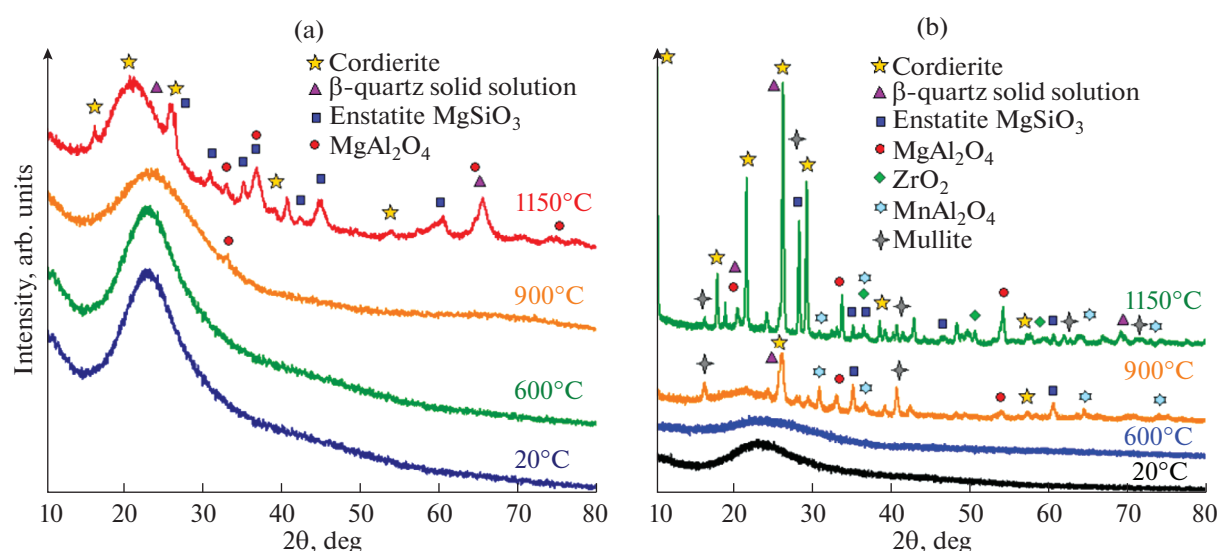


Fig. 2. X-ray diffraction patterns of sol–gel powders of the MgO–Al₂O₃–ZrO₂–SiO₂ system obtained from (a) gel **1**, not containing Mn, and (b) Mn-doped gel **2** heat treated at different temperatures.

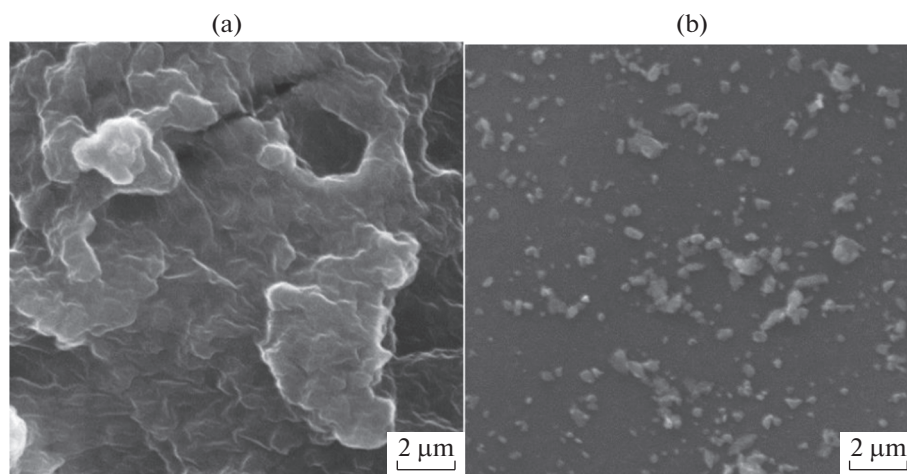


Fig. 3. SEM images of gel **1**, not containing Mn: (a) initial gel before heat treatment and (b) gel **1** heat treated at 1150°C.

shape of the emission bands suggests that they have a complex structure and are the result of the superposition of several luminescence bands of different intensities. The large number of different crystalline phases in the structure of the obtained materials (Fig. 2), the variability of the valence and coordination state of manganese ions, and the mutual overlap of various emission bands in the spectra make their identification difficult.

The strongest luminescence band with $\lambda_{\text{max}} \sim 410$ nm (Figs. 5a, 5b, curve 1) is observed when the material is excited under UV-C light ($\lambda_{\text{ex}} = 250$ nm). According to [22], the excitation of luminescence (Fig. 5a, 5b, curve 1) by UV-C light is related to the fundamental absorption of the matrix.

Crystals formed during the crystallization of materials of the RO–Al₂O₃–SiO₂ system (aluminum magnesium spinel; quartz-like solid solutions) can have intrinsic structural defects that determine the luminescence of the materials in the near-UV and blue ranges of the spectrum. For example, the luminescence spectra of aluminum magnesium spinel excited by short-wave UV light show strong bands with maxima at 316, 380, 400, and 460 nm [43]. This spectral range can also display the luminescence of structural defects described in detail in [44], characteristic of silica obtained by the sol–gel method. These data allow us to assume that structural defects in the resulting materials make the major contribution to the luminescence observed in the blue part of the spectrum.

A green luminescence band with a maximum at 525 nm, corresponding to Mn²⁺ in a tetrahedral environment, was observed in MgAl₂O₄ crystals upon excitation with blue light [15, 45]. The quantum efficiency of luminescence, according to [45], was quite high (45%). In the present work, we also observe luminescence bands in the green–yellow part of the spectrum (Figs. 5a, 5b), but their intensity is low. This phe-

nomenon can be explained by the relatively small content of spinel crystals in the structure of the resulting material.

In Mn²⁺-doped oxide materials, luminescence excitation in green ($\lambda \sim 500$ –540 nm; Figs. 5a, 5b, curve 2) and yellow–red ($\lambda \sim 560$ –660 nm; Fig. 5a, curves 3, 4; Fig. 5b, curves 3–5) spectral ranges are determined by the absorption bands of Mn²⁺ ions associated with electronic transitions from the ⁶A₁(⁶S) level to the ⁴T₂(⁴G), [⁴A₁(⁴G), ⁴E(⁴G)], ⁴E(⁴D), and ⁴T₂(⁴D) levels (Fig. 1) [20]. In addition, the emission observed in the red range of the spectrum can be associated with the partial oxidation of Mn²⁺ ions and the entry of the resulting Mn⁴⁺ ions into the lattice of spinel crystals [15, 33, 34]. At the same time, red luminescence can be due to the presence of structural defects in silica [44].

Comparison of emission bands (Figs. 5a, 5b, curves 1, 2) in the blue range of the spectrum ($\lambda = 400$ –460 nm) with luminescence excitation bands in the yellow–red region of the spectrum (Fig. 5a, curves 5, 6; Fig. 5b, curve 6) shows their significant overlap. This suggests the possibility of transfer of excitation energy between different luminescent centers or reabsorption of radiation in the material.

Figure 5c illustrates changes in the emission spectra of gel **2** with an increase in the temperature of its heat treatment from 900 to 1150°C. An increase in the heat treatment temperature, leading to the development of crystallization processes in the material (Fig. 2), determines an almost identical increase in luminescence intensity in the blue and green–yellow regions of the spectrum. The comparison of the difference spectra shown in this figure and the luminescence spectra shown in Figs. 5a and 5b demonstrates that the emission peaks have the same spectral position. This allows us to conclude that increasing heat treatment temperature leads to an increase in the concentration of already formed luminescent centers.

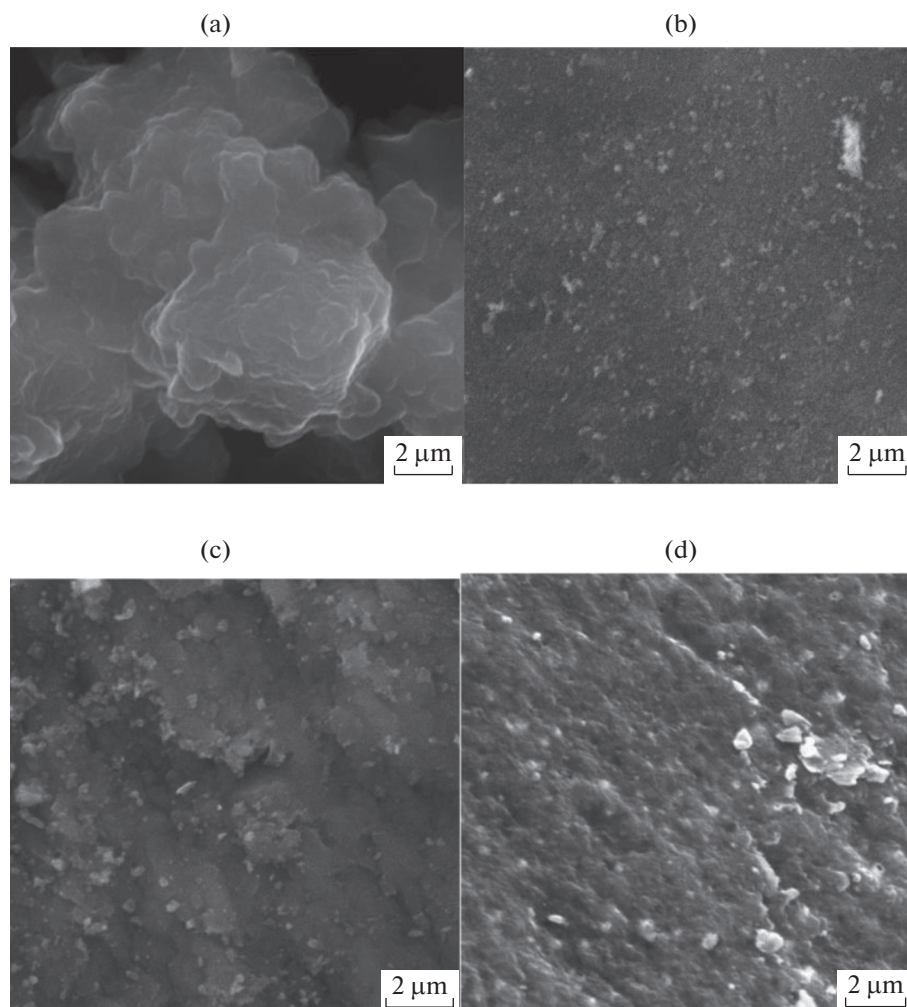


Fig. 4. SEM images of Mn-doped gel 2: (a) initial gel before heat treatment and (b–d) gel heat treated at (b) 600, (c) 900, and (d) 1150°C.

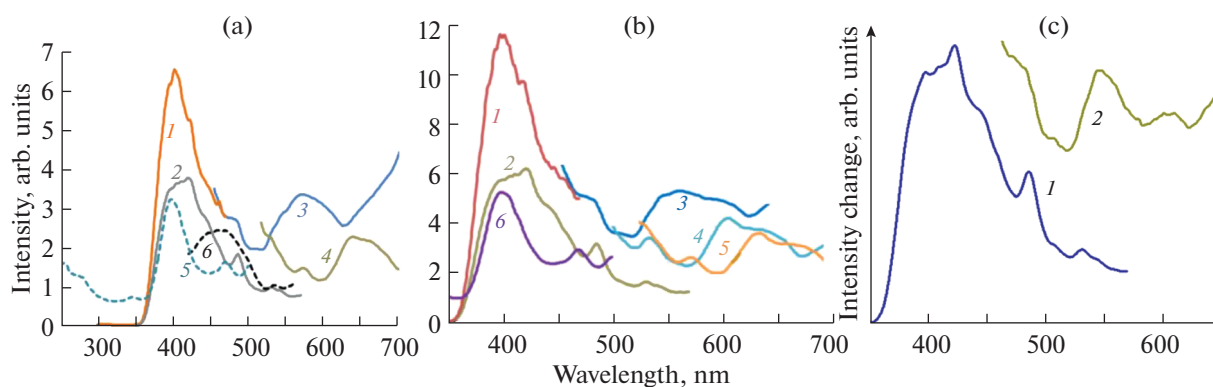


Fig. 5. (a) Emission (1–4) and luminescence excitation (5, 6) spectra of gel 2 heat treated at 900°C. The luminescence excitation wavelength: (1) 250, (2) 350, (3) 400, and (4) 480 nm. The emission wavelength: (5) 560 and (6) 640 nm. (b) Emission (1–5) and luminescence excitation (6) spectra of gel 2 heat treated at 1150°C. The luminescence excitation wavelength: (1) 250, (2) 300, (3) 400, (4) 450, and (5) 480 nm. The emission wavelength: (6) 560 nm. (c) Difference emission spectra (excitation wavelength (1) 350 and (2) 400 nm) of gel 2, which demonstrate changes in emission spectra of the gel with increasing heat treatment temperature from 900 to 1150°C.

Figure 5 shows that the resulting glass-ceramic materials based on the MgO–Al₂O₃–ZrO₂–SiO₂ system exhibit a combination of blue ($\lambda \sim 410\text{--}425$ nm) and yellow-red ($\lambda \sim 560\text{--}660$ nm) luminescence, which is optimal for their use in agricultural lighting systems to stimulate plant growth and development [36, 37]. The use of these heat-resistant, chemically stable, and inexpensive luminescent materials as phosphors in lighting technology of crop production is very promising.

CONSLUSIONS

Mn²⁺-doped MgO–Al₂O₃–ZrO₂–SiO₂ materials have been synthesized by the sol–gel method, and their morphology, structure, and luminescent properties have been studied. The introduction of Mn into the composition of materials significantly accelerates the crystallization processes during heat treatment of materials up to 1150°C. The use of Mn²⁺-doped luminescent materials of the MgO–Al₂O₃–ZrO₂–SiO₂ system as phosphors in lighting technology of plant production is very promising.

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CONFLICT OF INTEREST

The authors of this work declare that they have no conflicts of interest.

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